# User's Guide TPS56C230 Buck Converter Evaluation Module User's Guide

# TEXAS INSTRUMENTS

#### ABSTRACT

This user's guide contains information for the TPS56C230EVM evaluation module as well as for the TPS56C230 dc/dc converter. Also included are the performance specifications, schematic, layout and the list of materials for the TPS56C230EVM.

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# **1** Introduction

The TPS56C230 is a synchronous buck converter designed to provide up to a 12-A output. The input voltage is rated for 4.5 V to 18 V. The TPS56C230 uses a proprietary D-CAP3<sup>™</sup> control mode. It provides a fast transient response with no external compensation, and supports low ESR output capacitors. A MODE pin is used to set Forced Continuous Conduction Mode (FCCM) or Advanced Eco-mode operation. Rated input voltage and output current range for the evaluation module are given in Table 1-1. The high-side and low-side switching MOSFETs are integrated inside the TPS56C230 package along with the gate-driver circuitry. The low drain-to-source on resistance of the MOSFET allows the TPS56C230 to achieve high efficiencies and helps keep the junction temperature low at high output currents. An external divider allows for an adjustable output voltage. Additionally, the TPS56C230 provides adjustable soft start and undervoltage lockout inputs and an open drain power good output.

The TPS56C230EVM evaluation module (EVM) is a single, synchronous buck converter providing 1.2 V at 12 A from 4.5 V to 18 V input. This user's guide describes the TPS56C230EVM performance.

| EVM          | INPUT VOLTAGE<br>(V <sub>IN</sub> ) Range | OUTPUT CURRENT<br>(I <sub>OUT</sub> ) Range |
|--------------|---|---|
| TPS56C230EVM | 4.5 V to 18 V                             | 0 A to 12 A                                 |

#### Table 1-1. Input Voltage and Output Current Summary



# **2 Performance Specification Summary**

A summary of the TPS56C230EVM performance specifications is provided in Table 2-1. Specifications are given for an input voltage of 12 V and an output voltage of 1.2 V, unless otherwise specified. The ambient temperature is 25°C for all measurement, unless otherwise noted.

| SPECIFICATIONS                | TEST CONDITIO  | NS             | MIN  | TYP           | MAX | UNIT   |
|-------------------------------|--|----------------|------|---------------|-----|--------|
| V <sub>IN</sub> Input voltage |  |                | 4.5  | 12            | 18  | V      |
| V <sub>IN</sub> start voltage |  |                | Int  | Internal UVLO |     |        |
| V <sub>IN</sub> stop voltage  |  |                | Int  | Internal UVLO |     |        |
| Output voltage setpoint       |  |                |      | 1.2           |     | V      |
| Output current range          | V <sub>IN</sub> = 4.5 V to 18 V                              |                | 0    |               | 12  | А      |
| Line regulation               | I <sub>OUT</sub> = 6 A, V <sub>IN</sub> = 4.5 V to 17 V      |                |      | ± 0.05%       | )   |        |
| Load regulation               | V <sub>IN</sub> = 12 V, I <sub>OUT</sub> = 0 to 12 A         |                | -0.0 | )2%, +0.      | 25% |        |
|                               | I <sub>OUT</sub> = 1.2 A to 10.8 A                           | Voltage change |      | -38           |     | mV     |
| I                             |  | Recovery time  |      | 75            |     | μs     |
| Load transient response       |  | Voltage change |      | 48            |     | mV     |
|                               | $I_{OUT} = 10.8 \text{ A to } 1.2 \text{ A}$                 | Recovery time  |      | 50            |     | μs     |
| Loop bandwidth                | V <sub>IN</sub> = 12 V, I <sub>OUT</sub> = 6 A               |                |      | 126.5         |     | kHz    |
| Phase margin                  | V <sub>IN</sub> = 12 V, I <sub>OUT</sub> = 6 A               |                |      | 72.5          |     | degree |
| Input ripple voltage          | V <sub>IN</sub> = 12 V, I <sub>OUT</sub> = 12 A              |                |      | 290           |     | mVPP   |
| Output ripple voltage         | V <sub>IN</sub> = 12 V, I <sub>OUT</sub> = 12 A              |                |      | 16            |     | mVPP   |
| Output rise time              | Soft start pin floating                                      |                |      | 1.5           |     | ms     |
| Maximum efficiency            | TPS56C230EVM, V <sub>IN</sub> = 12 V, I <sub>OUT</sub> = 4 A |                |      | 89.75%        |     |        |

#### Table 2-1. TPS56C230EVM Performance Specifications Summary



# **3 Modifications**

The evaluation module is designed to provide access to the features of the TPS56C230. Some modifications can be made to this module.

# 3.1 Output Voltage Setpoint

The output voltage is set by the resistor divider network of R4 ( $R_{TOP}$ ) and R6 ( $R_{BOT}$ ). R6 is fixed at 10.0 k $\Omega$ . To change the output voltage of the EVM, it is necessary to change the value of resistor R4. Changing the value of R4 can change the output voltage above the 0.6 V reference voltage V<sub>REF</sub>. The value of R4 for a specific output voltage can be calculated using Equation 1.

$$R_{(TOP)} = \frac{R_{(BOT)} \cdot (V_{OUT} - V_{REF})}{V_{REF}}$$
(1)

### 3.2 Mode Selection

TPS56C230 has a MODE pin to select the operation mode. The device reads the voltage on MODE pin during start-up and latches onto one of the MODE options listed below in Table 3-1.

| VOLTAGE ON MODE | R9/10/11/12 (kΩ) | R13/14/15/16 (kΩ) | OPERATION | FREQUENCY (kHz) |
|-----------------|------------------|-------------------|-----------|-----------------|
| (0~10%)*VCC     | 330              | 15                | Eco-mode  | 500             |
| (10~20%)*VCC    | 180              | 33                | FCCM      | 500             |

#### Table 3-1. Mode Pin Resistor Settings

Change the position of the jumper on J4 to modify the MODE configuration before start up.



# 4 Test Setup and Results

This section describes how to properly connect, set up, and use the TPS56C230EVM evaluation module. The section also includes test results typical for the evaluation module and covers efficiency, output voltage regulation, line regulation, load transient response, output voltage ripple, input voltage ripple, start-up and power-off.

#### 4.1 Input/Output Connections

The TPS56C230EVM is provided with input/output connectors and test points as shown in Table 4-1. A power supply capable of supplying greater than 5 A must be connected to J1 through a pair of 20-AWG wires or better. The load must be connected to J2 through a pair of 20-AWG wires. The maximum load current capability is 12 A. Wire lengths must be minimized to reduce losses in the wires. Test point TP3 provides a place to monitor the  $V_{IN}$  input voltages with TP8 providing a convenient ground reference. TP5 is used to monitor the output voltage with TP11 as the ground reference.

| REFERENCE<br>DESIGNATOR | FUNCTION   |
|-------------------------|--|
| J1                      | V <sub>IN</sub> input connector. (see Table 1-1 for V <sub>IN</sub> range)                   |
| J2                      | V <sub>OUT</sub> output connector. 1.2 V at 12 A maximum.                                    |
| J3                      | Soft start selection. Remove the shunt to set the soft start time as internal default value. |
| J4                      | MODE selection. Refer to Section 3.2.  |
| J5                      | EN control. Shunt EN to GND to disable. Shunt EN to the other side to enable.                |
| TP1                     | VCC  |
| TP2                     | V <sub>IN</sub> terminal   |
| TP3                     | V <sub>IN</sub> test point   |
| TP4                     | V <sub>OUT</sub> terminal  |
| TP5                     | V <sub>OUT</sub> test point  |
| TP6                     | SW node test point   |
| TP7                     | Test point between voltage divider network and output. Used for loop response measurements.  |
| TP8~11                  | GND test point   |
| TP12                    | PGOOD test point   |
| TP13~15                 | GND test point   |
| TP16                    | EN test point  |

| Table | 4-1     | Connection | and | Test | Points  |
|-------|---------|------------|-----|------|---------|
| lable | <b></b> | Connection | anu | iesi | i onita |

### 4.2 Efficiency

Figure 4-1 shows the efficiency for the TPS56C230EVM in 500kHz/Eco mode. The ambient temperature is 25 °C.



Figure 4-1. TPS56C230EVM Efficiency at 500-kHz/Eco mode

Figure 4-2 shows the efficiency at light loads for the TPS56C230EVM using a semi-log scale. The ambient temperature is 25 °C.



Figure 4-2. TPS56C230EVM Light Load Efficiency at 500-kHz/Eco Mode

The efficiency may be lower at higher ambient temperature, due to temperature variation in the drain-to-source resistance of the internal MOSFET.

# 4.3 Output Voltage Load Regulation

Figure 4-3 shows the load regulation for the TPS56C230EVM. Measurement is given for an ambient temperature of 25 °C.





### 4.4 Output Voltage Line Regulation

Figure 4-4 shows the line regulation for the TPS56C230EVM. Measurement is given for an ambient temperature of 25 °C.







# 4.5 Load Transient Response

The TPS56C230EVM response to load transient is shown in Figure 4-5. The current steps and slew rates are indicated in the following figures . Total peak-to-peak voltage variation is as shown, including ripple and noise on the output.





Figure 4-5. TPS56C230EVM Load Transient Response



# 4.6 Output Voltage Ripple

Figure 4-6, Figure 4-7, Figure 4-8 show the TPS56C230EVM output voltage ripple. The load currents are 10 mA, 800 mA, and 12 A.  $V_{IN}$  = 12 V. The ripple voltage is measured directly across TP5 and TP11.







Time = 2 μsec / div

Figure 4-7. TPS56C230EVM Output Ripple, 800-mA Load



Time =  $2 \mu sec / div$ 

Figure 4-8. TPS56C230EVM Output Ripple, 12-A Load



# 4.7 Input Voltage Ripple

Figure 4-9, Figure 4-10 and Figure 4-11 show the TPS56C230EVM input voltage ripple at 500 kHz Eco-mode. The load currents are 10 mA, 800 mA and 12 A. The ripple voltage is measured directly across TP3 and TP8.













 $fine = 2 \mu sec / uiv$ 

Figure 4-11. TPS56C230EVM Input Ripple, 12-A Load

# 4.8 Loop Characteristics

Figure 4-12 shows the TPS56C230EVM loop-response characteristics. Gain and phase plots are shown for  $V_{IN}$  voltage of 12 V. Load current for the measurement is 12 A.





Figure 4-12. TPS56C230EVM Loop Response

# 4.9 Start-Up

Figure 4-13 and Figure 4-14 show the start-up waveforms for the TPS56C230EVM. In Figure 4-13, the output voltage ramps up as soon as the input voltage reaches the UVLO threshold. In Figure 4-14, the input voltage is initially applied and the output is inhibited by using a jumper at J5 to tie EN to GND. When the jumper is removed, EN is released. When the EN voltage reaches the enable-threshold voltage, the start-up sequence begins and the output voltage ramps up to the externally set value of 1.2 V. The input voltage for these plots is 12 V and the load is 1  $\Omega$ .



Time = 2 msec / div





Time = 2 msec / div

Figure 4-14. TPS56C230EVM Start-Up Relative to Enable



# 4.10 Shut-Down

Figure 4-15 and Figure 4-16 show the shutdown waveforms for the TPS56C230EVM. The input voltage for these plots is 12V and the load is  $1\Omega$ .



Time = 2 msec / div



|                    | Û |                                       |           |             |               |  |
|--------------------|---|---------------------------------------|-----------|-------------|---------------|--|
| Vin = 10V / div    |   | · · · · · ·                           |           | · · · · · · | · · · · · · · |  |
| EN = 5V / div      |   | · · · · · · · · · · · · · · · · · · · | - · · · · | · · · · · · |               |  |
| Vout = 500mV / div |   |                                       |           | ++++        |               |  |
|                    |   |                                       |           |             |               |  |
| PG = 5V / div      |   |                                       |           |             |               |  |

Time = 2 msec / div

Figure 4-16. Shutdown Relative to Enable



# **5 Board Layout**

This section provides a description of the TPS56C230EVM, board layout and layer illustrations.

#### 5.1 Layout

The board layout for the TPS56C230EVM is shown in Figure 5-1 through Figure 5-5. The top and bottom layers are 2-oz copper thickness. Internal layers are 1-oz copper thickness.

The top layer contains the main power traces for VIN, VOUT and ground. Also on the top layer are connections for the pins of the TPS56C230 and a large area filled with ground. Most of the signal traces are located on the bottom left side, surrounding by a ground plane with an island for quiet analog ground that is connected to the main power ground at a single point. The internal layer-1 and internal layer-2 are dedicated ground planes. The bottom layer is another ground copper area with additional SW, VIN and VOUT copper fill. Ground traces on different layers are connected to each other with multiple vias placed on the board.

The input decoupling capacitors are located as close to the IC as possible. Critical analog circuits, such as the voltage set point divider, EN resister, SS capacitor, Mode resistor, VCC and AGND pin are terminated to quiet analog ground island on the top layer. The input and output connectors, test points and all of the components are located on the top side. The bottom layer is a ground plane along with the switching node copper fill, VIN and VOUT copper fill and the feedback trace from the point of regulation to the top of the resistor divider network.



Figure 5-1. TPS56C230EVM Top-Side Assembly





Figure 5-2. TPS56C230EVM Top-Side Layout

















# 6 Schematic, List of Materials, and Reference

# 6.1 Schematic

Figure 6-1 shows the schematic for TPS56C230EVM.







# 6.2 List of Materials

Table 6-1 presents the list of materials for the TPS56C230EVM.

| Table 6-1. TPS56C230EVM List | t of Materials |
|------------------------------|----------------|
|------------------------------|----------------|

| DES                                       | QTY | DESCRIPTION  | PART NUMBER         | MANUFACTURER                   |
|---|-----|--|---------------------|--------------------------------|
| IPCB1                                     | 1   | Printed circuit board  | BSR062              | Any                            |
| C1  | 1   | Capacitor ceramic, 1 µF, 25 V, ±10%, X5R, 0603   | C1608X5R1E105K080AC | ток                            |
| C2, C6, C7, C15                           | 4   | Capacitor ceramic, 0.1 µF, 50 V, ±10%, X7R, 0603   | C1608X7R1H104K080AA | ток                            |
| C4, C5                                    | 2   | Capacitor ceramic, 22 μF, 35 V, ±20%, X5R, 1206  | C3216X5R1V226M160AC | TDK                            |
| C8, C9, C10,<br>C11                       | 4   | Capacitor ceramic, 47 µF, 10 V, ±20%, X5R, 0805  | GRM21BR61A476ME15L  | MuRata                         |
| C14                                       | 1   | Capacitor ceramic, 0.018 µF, 16 V, ±10%, X7R, 0603                                       | GRM188R71C183KA01D  | MuRata                         |
| D1  | 1   | Diode, Zener, 5.1 V, 500 mW, SOD-123   | MMSZ5231B-7-F       | Diodes Inc.                    |
| H1, H2, H3, H4                            | 4   | Bumpon, hemisphere, 0.44 X 0.20, clear   | SJ-5303 (CLEAR)     | 3M                             |
| J1, J2                                    | 2   | Terminal block, 5.08 mm, 2x1, brass, TH  | ED120/2DS           | On-Shore Technology            |
| J3  | 1   | Header, 100 mil, 2x1, tin, TH  | PEC02SAAN           | Sullins Connector<br>Solutions |
| J4  | 1   | Header, 100 mil, 4x2, tin, TH  | PEC04DAAN           | Sullins Connector<br>Solutions |
| J5  | 1   | Header, 100 mil, 3x1, tin, TH  | PEC03SAAN           | Sullins Connector<br>Solutions |
| L1  | 1   | Inductor, shielded drum core, powdered iron, 680 nH, 17.5<br>A, 0.0018 ohm, SMD          | 744373770068        | Wurth Elektronik               |
| R1  | 1   | Resistor, 0 Ω, 5%, 0.1 W, AEC-Q200 grade 0, 0603   | CRCW06030000Z0EA    | Vishay-Dale                    |
| ₹2  | 1   | Resistor, 51.1 Ω, 1%, 0.1 W, AEC-Q200 grade 0, 0603                                      | CRCW060351R1FKEA    | Vishay-Dale                    |
| R4, R6                                    | 2   | Resistor, 10.0 kΩ, 1%, 0.1 W, AEC-Q200 grade 0, 0603                                     | CRCW060310K0FKEA    | Vishay-Dale                    |
| २5  | 1   | Resistor, 100 kΩ, 1%, 0.1 W, AEC-Q200 grade 0, 0603                                      | CRCW0603100KFKEA    | Vishay-Dale                    |
| R7, R8                                    | 2   | Resistor, 51 kΩ, 5%, 0.1 W, AEC-Q200 grade 0, 0603                                       | CRCW060351K0JNEA    | Vishay-Dale                    |
| २9  | 1   | Resistor, 330 kΩ, 5%, 0.1 W, AEC-Q200 grade 0, 0603                                      | CRCW0603330KJNEA    | Vishay-Dale                    |
| R10                                       | 1   | Resistor, 180 kΩ, 1%, 0.1 W, AEC-Q200 grade 0, 0603                                      | CRCW0603180KJNEA    | Vishay-Dale                    |
| R13                                       | 1   | Resistor, 15 kΩ, 5%, 0.1 W, AEC-Q200 grade 0, 0603                                       | CRCW060315K0JNEA    | Vishay-Dale                    |
| २14                                       | 1   | Resistor, 33 kΩ, 5%, 0.1 W, AEC-Q200 grade 0, 0603                                       | CRCW060333K0JNEA    | Vishay-Dale                    |
| SH-J1, SH-J2,<br>SH-J3                    | 3   | Shunt, 100 mil, gold plated, black   | SNT-100-BK-G        | Samtec                         |
| TP1, TP3, TP5,<br>TP6, TP7, TP12,<br>TP16 | 7   | Test point, miniature, red, TH   | 5000                | Keystone                       |
| TP2, TP4, TP9,<br>TP10                    | 4   | Terminal, turret, TH, triple   | 1598-2              | Keystone                       |
| TP8, TP11,<br>TP13, TP14,<br>TP15         | 5   | Test point, miniature, black, TH   | 5001                | Keystone                       |
| U1  | 1   | 4.5-V to 18-V Input, 12-A Synchronous Step-Down Voltage<br>Regulator, RJE0020B (VQFN-20) | TPS56C230RJER       | Texas Instruments              |
| C3  | 0   | Capacitor ceramic, 22 µF, 35 V, ±20%, X5R, 1206  | C3216X5R1V226M160AC | TDK                            |
| C12                                       | 0   | Capacitor ceramic, 47 µF, 10 V, ±20%, X5R, 0805  | GRM21BR61A476ME15L  | MuRata                         |
| C13                                       | 0   | Capacitor ceramic, 100 pF, 25 V, ±10%, X7R, 0603   | 06033C101KAT2A      | AVX                            |
| FID1, FID2, FID3                          | 0   | Fiducial mark. There is nothing to buy or mount.   | N/A                 | N/A                            |
| R3  | 0   | Resistor, 0 Ω, 5%, 0.1 W, AEC-Q200 grade 0, 0603   | CRCW06030000Z0EA    | Vishay-Dale                    |
| ٦11                                       | 0   | Resistor, 160 kΩ, 5%, 0.1 W, AEC-Q200 grade 0, 0603                                      | CRCW0603160KJNEA    | Vishay-Dale                    |
| R12                                       | 0   | Resistor, 75 kΩ, 5%, 0.1 W, AEC-Q200 grade 0, 0603                                       | CRCW060375K0JNEA    | Vishay-Dale                    |
| R15, R16                                  | 0   | Resistor, 51 kΩ, 5%, 0.1 W, AEC-Q200 grade 0, 0603                                       | CRCW060351K0JNEA    | Vishay-Dale                    |



**7 Revision History** NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| Cł | nanges from Revision A (September 2019) to Revision B (June 2021)                              | Page |
|----|--|------|
| •  | Updated user's guide title   | 2    |
|    | Updated the numbering format for tables, figures, and cross-references throughout the document |      |
| Cł | nanges from Revision * (January 2019 September 2019) to Revision A ()                          | Page |
| •  | Added updated List of Materials  |      |

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